## V20DM120C-M3, V20DM120CHM3

Vishay General Semiconductor

## **Dual Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.55$  V at  $I_F = 5$  A



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#### V20DM120C

# PIN 1 O

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 10 A			
V <sub>RRM</sub>	120 V			
I <sub>FSM</sub>	120 A			
$V_F$ at $I_F$ = 10 A ( $T_A$ = 125 °C)	0.65 V			
T <sub>J</sub> max.	175 °C			
Package	TO-263AC (SMPD)			
Diode variations	Dual common cathode			

### FEATURES

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
   Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, inductrial, and automotive application.

### **MECHANICAL DATA**

#### Case: TO-263AC SMPD

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test **Polarity:** As marked

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V20DM120C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	120	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	20	٥	
	per diode		10	A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	120	А	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +175	°C	



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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> (1)	0.65	-	V	
	I <sub>F</sub> = 10 A			0.85	0.93		
	I <sub>F</sub> = 5 A	- T <sub>A</sub> = 125 °C		0.55	-		
	I <sub>F</sub> = 10 A			0.65	0.73		
Reverse current at rated V <sub>R</sub> per diode	V <sub>B</sub> = 90 V	$T_{A} = 25 ^{\circ}C$	I <sub>R</sub> <sup>(2)</sup>	23	-	μA	
	v <sub>R</sub> = 90 v	T <sub>A</sub> = 125 °C		1.6	-	mA	
	$V_{-} = 120 V_{-}$	T <sub>A</sub> = 25 °C		-	600	μA	
	V <sub>R</sub> = 120 V	T <sub>A</sub> = 125 °C		3	20	mA	

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V20DM120C	UNIT	
Typical thermal resistance	per diode	$R_{ extsf{ heta}JC}$	2.8		
	per device		1.5	°C/W	
	per device	R <sub>0JA</sub> <sup>(1)(2)</sup>	48		

#### Notes

<sup>(1)</sup> The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

<sup>(2)</sup> Free air, without heatsink

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AC (SMPD)	V20DM120C-M3/I	0.55	Ι	2000/reel	13" diameter plastic tape and reel
TO-263AC (SMPD)	V20DM120CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel

#### Note

(1) AEC-Q101 qualified



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### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

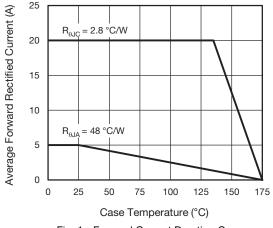


Fig. 1 - Forward Current Derating Curve

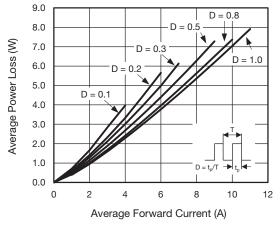


Fig. 2 - Forward Power Loss Characteristics Per Diode

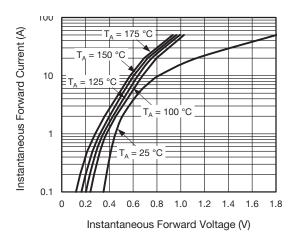
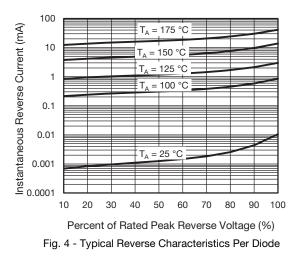


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode



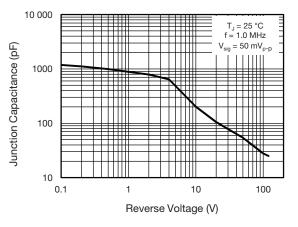


Fig. 5 - Typical Junction Capacitance Per Diode

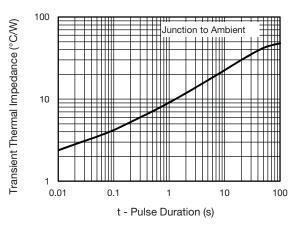


Fig. 6 - Typical Transient Thermal Impedance Per Device

 Revision: 02-Apr-15
 3
 Document Number: 89989

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## V20DM120C-M3, V20DM120CHM3

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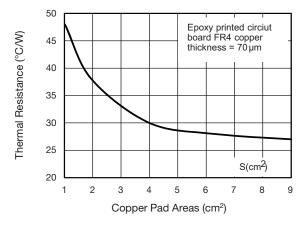
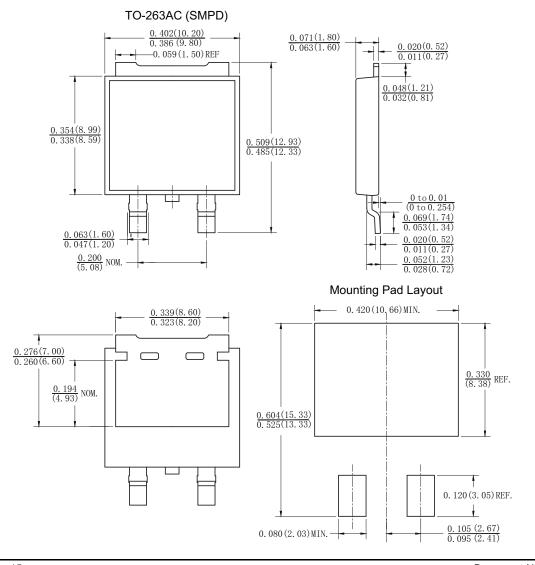


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



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